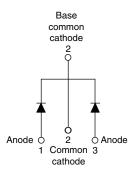


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Schottky Rectifier, 2 x 30 A

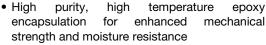




PRODUCT SUMMARY						
Package	TO-220AB					
I _{F(AV)}	2 x 30 A					
V_{R}	150 V					
V _F at I _F	0.72 V					
I _{RM} max.	20 mA at 125 °C					
T _J max.	175 °C					
Diode variation	Common cathode					
E _{AS}	0.4 mJ					

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC-JESD47
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-60CTQ150... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Rectangular waveform	60	А				
V_{RRM}		150	V				
I _{FSM}	t _p = 5 μs sine	710	A				
V _F	30 A _{pk} , T _J = 125 °C (typical, per leg)	0.69	V				
T _J	Range	- 55 to 175	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-60CTQ150PbF	VS-60CTQ150-N3	UNITS		
Maximum DC reverse voltage	V _R	150	150	V		
Maximum working peak reverse voltage	V _{RWM}	150	150	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	TEST CONDITIONS			
Maximum average per leg		50 % duty cycle at T _C = 137 °C, rectangular waveform		30		
See fig. 5 per device	I _{F(AV)}			60		
Maximum peak one cycle non-repetitive	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and	710	A	
surge current per leg See fig. 7		10 ms sine or 6 ms rect. pulse	with rated V _{RRM} applied	270		
Non-repetitive avalanche energy per leg		$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.9 \text{A}, L = 1 \text{mH}$		0.4	mJ	
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.9	Α	



VS-60CTQ150PbF, VS-60CTQ150-N3

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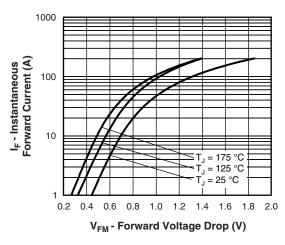
ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS
Maximum forward voltage drop per leg See fig. 1		30 A	T 05 00	0.83	0.88	
	V _{FM} ⁽¹⁾	60 A	T _J = 25 °C	0.98	1.09	V
		30 A	T 105 °C	0.67	0.72	V
		60 A	T _J = 125 °C	0.82	0.87	
Maximum reverse leakage current per leg	I _{RM}	T _J = 25 °C	V _R = Rated V _R	7	75	μA
See fig. 2		T _J = 125 °C	V _R = nateu V _R	7.2	20	mA
Typical junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		-	650	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		-	7.5	nH
Maximum voltage rate of change	dV/dt	Rated V _R	-	10 000	V/µs	

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS		
Maximum junction and storage temperature range)	T _J , T _{Stg}		- 55 to 175	°C		
Maximum thermal resistance,	per leg	В	DC operation See fig. 4	1.2			
junction to case	per package	R_{thJC}	DC operation	0.6	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.25			
Annyovimata wajaht				6	g		
Approximate weight				0.21	OZ.		
minimum				6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf · in)		
Marking device			Case style TO-220AB	60CTQ150			

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100 = 175 °C T₁ = 150 °C IR - Reverse Current (mA) 10 = 125 °C $T_1 = 100 \, ^{\circ}C$ 75 0.1 = 50 0.01 = 25 °C 0.001 80 20 60 100 120 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

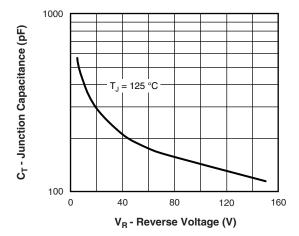


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

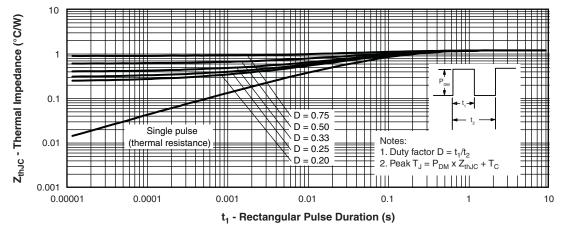


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)



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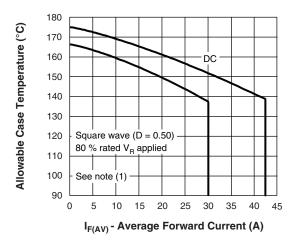


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

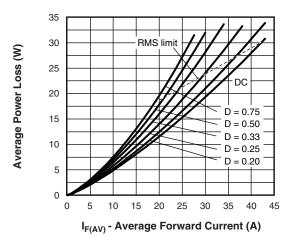


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

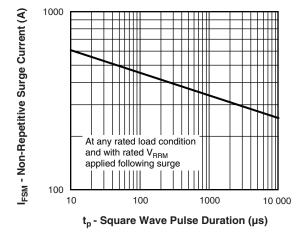


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

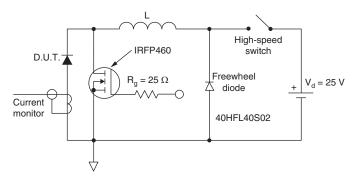


Fig. 8 - Unclamped Inductive Test Circuit

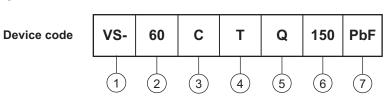
Note

Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = 80$ % rated V_R

VS-60CTQ150PbF, VS-60CTQ150-N3

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ORDERING INFORMATION TABLE



- 1 Vishay Semiconductors product
- 2 Current rating (60 = 60 A)
- Circuit configuration

C = Common cathode

4 - Package

T = TO-220

- 5 Schottky "Q" series
- 6 Voltage rating (150 = 150 V)
- 7 Environmental digit
 - PbF = Lead (Pb)-free and RoHS compliant
 - -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-60CTQ150PbF	50	1000	Antistatic plastic tube				
VS-60CTQ150-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Dort marking information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



Legal Disclaimer Notice

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